



600V N-Channel MOSFET

Voltage

600 V

Current

12 A

Features

- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@6A<0.7\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

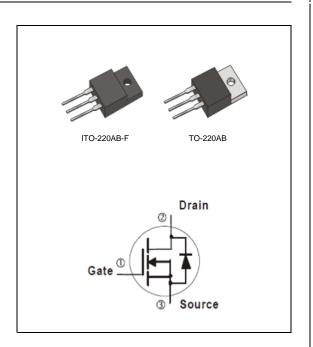


• Case: TO-220AB, ITO-220AB-F Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• TO-220AB Approx. Weight: 0.067 ounces, 1.89 grams

• ITO-220AB-F Approx. Weight: 0.068 ounces, 2 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	TO-220AB	ITO-220AB-F	UNITS
Drain-Source Voltage		V_{DS}	600	V	
Gate-Source Voltage		V_{GS}	<u>+</u> 30	V	
Continuous Drain Current		I _D	12		А
Pulsed Drain Current		I _{DM}	48		А
Single Pulse Avalanche Energy (Note 1)		E _{AS}	795		mJ
Power Dissipation	T _C =25°C	P _D	225	51	W
	Derate above 25°C		1.8	0.41	W/°C
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150		°C
Typical Thermal resistance					
- Junction to Case		$R_{ heta JC}$	0.56	2.45	°C/W
- Junction to Ambient		$R_{\theta JA}$	62.5	120	

• Limited only By Maximum Junction Temperature





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V,I _D =250uA	600	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	2	2.96	4	V
Drain-Source On-State Resistance	R _{DS(on)}	V_{GS} =10V, I_D =6A	-	0.59	0.7	Ω
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =600V,V _{GS} =0V	-	0.02	1	uA
Gate-Source Leakage Current	I _{GSS}	$V_{GS}=\underline{+}30V, V_{DS}=0V$	-	<u>+</u> 10	<u>+</u> 100	nA
Diode Forward Voltage	V_{SD}	I _S =12A,V _{GS} =0V	-	0.85	1.4	V
Dynamic (Note 4)						
Total Gate Charge	Q_g	\/ 400\/ L 40A	-	24	-	nC
Gate-Source Charge	Q_gs	V_{DS} =480V, I_{D} =12A, V_{GS} =10V (Note 2,3)	-	7.8	-	
Gate-Drain Charge	Q_gd	V _{GS} =10V	-	7.4	-	
Input Capacitance	Ciss	\\ O5\\ \\ O\\	-	1492	-	
Output Capacitance	Coss V _{DS} =25V, V _{GS} =0V,		-	167	-	pF
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	4.5	-	
Turn-On Delay Time	td _(on)	V _{DD} =300V, I _D =12A,	-	37	-	ns
Turn-On Rise Time	t _r	$R_G=25\Omega$	-	72	-	
Turn-Off Delay Time	td _(off)	(Note 2,3)	-	81	-	
Turn-Off Fall Time	t _f		-	44	-	
Drain-Source Diode						
Maximum Continuous Drain-Source			-	-	12	А
Diode Forward Current	I _S					
Maximum Pulsed Drain-Source					48	Α
Diode Forward Current	I _{SM}		-	-	40	^
Reverse Recovery Time	trr	V _{GS} =0V, I _S =12A	-	574	-	ns
Reverse Recovery Charge	Qrr	$dI_F/dt=100A/us^{(Note 2)}$	-	5.4	-	uC

NOTES:

- 1. L=30mH, I_{AS} =7.1A, V_{DD} =50V, R_{G} =25ohm, Starting T_{J} =25 $^{\circ}$ C
- 2. Pulse width<300us, Duty cycle<2%
- 3. Essentially independent of operating temperature typical characteristics.
- 4. Guaranteed by design, not subject to production testing





TYPICAL CHARACTERISTIC CURVES

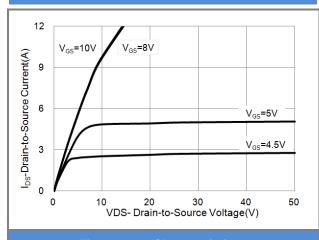


Fig.1 Output Characteristics

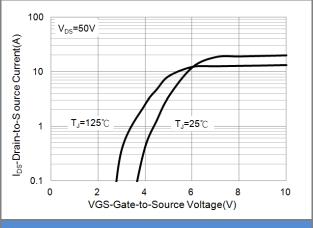


Fig.2 Transfer Characteristics

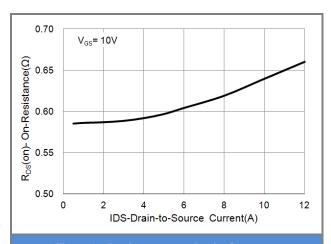


Fig.3 On-Resistance vs. Drain Current

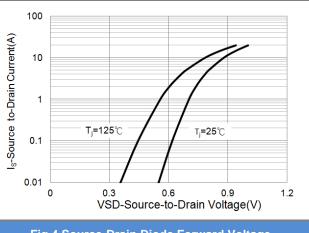
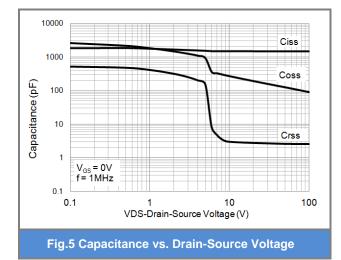
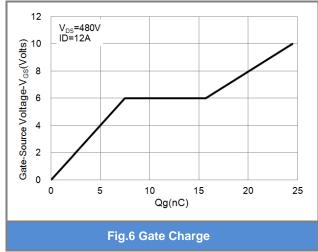


Fig.4 Source-Drain Diode Forward Voltage









TYPICAL CHARACTERISTIC CURVES

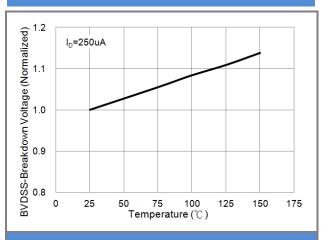


Fig.7 BV_{DSS} vs. Junction Temperature

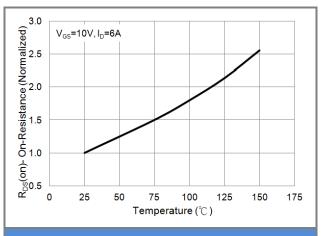


Fig.8 On-Resistance vs. Junction Temperature

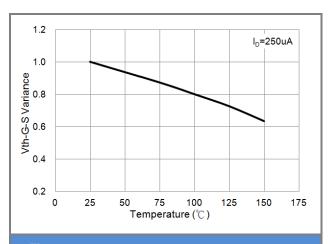


Fig.9 Threshold Voltage Variation with Temperature

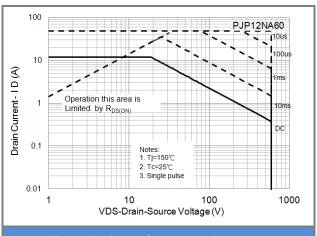


Fig.10 Maximum Safe Operating Area

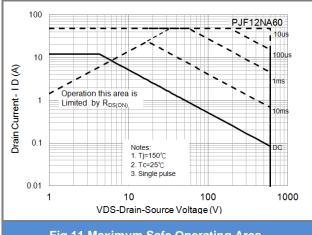


Fig.11 Maximum Safe Operating Area





TYPICAL CHARACTERISTIC CURVES

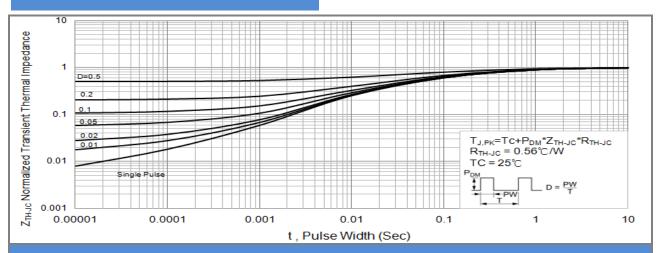


Fig.13 PJP12NA60 Normalized Transient Thermal Impedance vs. Pulse Width

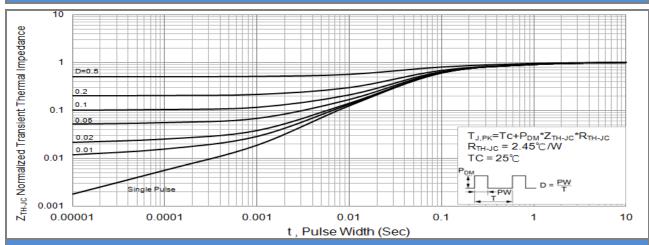
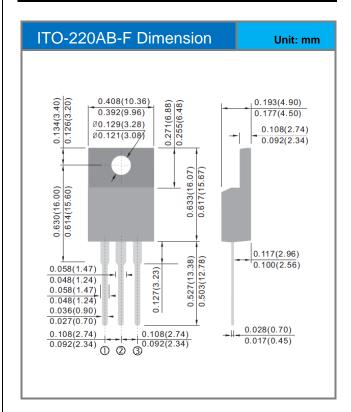


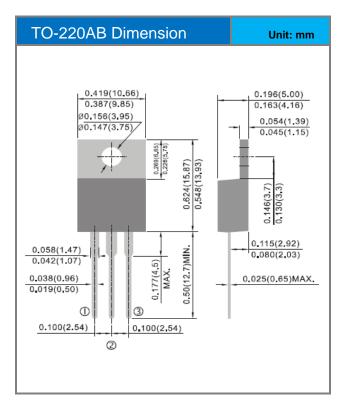
Fig.14 PJF12NA60 Normalized Transient Thermal Impedance vs. Pulse Width





Packaging Information









PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJP12NA60_T0_00001	TO-220AB	50pcs / Tube	P12NA60	Halogen free
PJF12NA60_T0_00001	ITO-220AB-F	50pcs / Tube	F12NA60	Halogen free





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